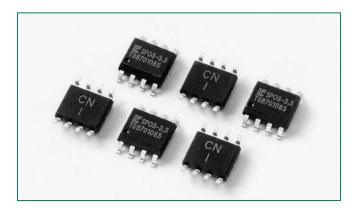


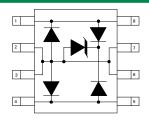
RoHS P GREEN SP03-3.3 (SO-8) Series



Agency Approvals - Pending

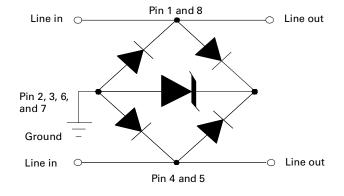
Agency	Agency File Number
89U	E128662

Pinout



SO-8 (Top View)

Functional Block Diagram



Description

This new broadband protection device from Littelfuse provides overvoltage protection for applications such as 10/100/1000 BaseT Ethernet, T3/E3 DS3 interfaces, ADSL2+, and VDSL2+. This new protector combines the TVS diode element with a diode rectifier bridge to provide both longitudinal and differential protection in one package. This design innovation results in a capacitive loading characteristic that is log-linear with respect to the signal voltage across the device. This reduces intermodulation (IM) distortion caused by a typical solid-state protection solution. The application schematic provides the connection information.

Features

- RoHS compliant
- MS-012 surface mount package (JEDEC SO-8)
- Low insertion loss, loglinear capacitance
- Combined longitudinal and metallic protection
- Lightning Protection, IEC61000-4-5, 100A (8/20µs)
- Clamping speed of nanoseconds
- UL 94V-0 epoxy molding
- Pending UL recognized component
- Low clamping voltage

Applications

- T1/E1 Line cards
- T3/E3 and DS3 Interfaces
- STS-1 Interfaces
- 10/100/1000 BaseT Ethernet

SPA[™] Silicon Protection Arrays

Low Capacitance TVS protection for high-speed data interfaces



Absolute Maximum Ratings

Parameter	Rating	Units
Peak Pulse Current (8/20µs)	150	А
Peak Pulse Power (8/20µs)	3300	W
IEC 61000-4-2, Direct Discharge, (Level 4)	30	kV
IEC 61000-4-2, Air Discharge, (Level 4)	30	kV
Telcordia GR 1089 (Intra-Building) (2/10µs)	100	А
ITU K.20 (5/310µs)	40	А

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

Thermal Information

Parameter	Rating	Units
SOIC Package	170	°C/W
Operating Temperature Range	-55 to 125	°C
Storage Temperature Range	-65 to 150	°C
Maximum Junction Temperature	150	°C
Maximum Lead Temperature (Soldering 10s) (SOIC - Lead Tips Only)	300	°C

Electrical Characteristics (T_{OP} = 25°C)

Parameter	Symbol	Test Conditions	Min	Тур	Max	Units
Reverse Stand-Off Voltage	V _{RWM}	-	-	-	3.3	V
Reverse Breakdown Voltage	V _{BR}	I _τ = 2μΑ	3.3	-	-	V
Reverse Breakdown Voltage	V _{BR}	Ι _τ = 50μΑ	3.3	-	-	V
Reverse Leakage Current	I _R	V _{RWM} = 3.3V, T= 25°C	-	-	1	μΑ
Clamping Voltage, Line-Ground	V _C	I _{PP} = 50A, t _p =8/20 μs	-	-	11.5	V
Clamping Voltage, Line-Ground	V _C	I_{pp} = 100A, t_p =8/20 µs	-	-	15	V
Clamping Voltage, Line-Line	V _C	I _{PP} = 50A, t _p =8/20 μs	-	-	13.5	V
Clamping Voltage, Line-Line	V _C	I_{pp} = 100A, t_p =8/20 µs	-	-	18	V
hunding Consider		Between I/O Pins and Ground $V_R=0V$, f= 1MHz	-	16	25	pF
Junction Capacitance	C _j	Between I/O Pins V _R =0V, f= 1MHz	-	8	12	pF



Figure 1: Non-repetitive Peak Pulse Current vs. Pulse Time



Figure 2: Current Derating Curve

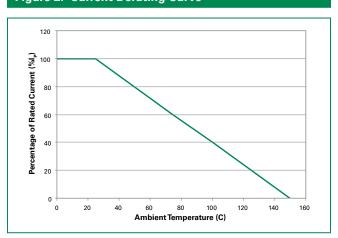


Figure 3: Pulse Waveform

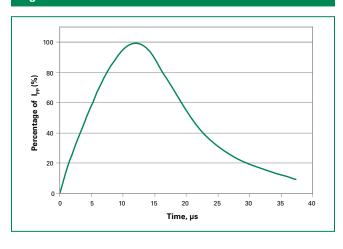


Figure 4: Clamping Voltage vs. Peak Pulse Current

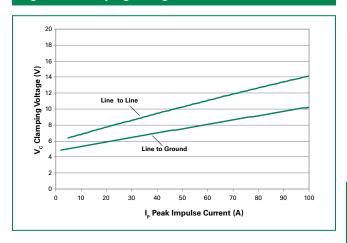


Figure 5: Capacitance vs. Reverse Voltage

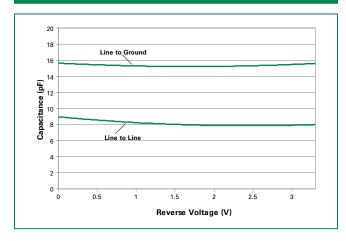
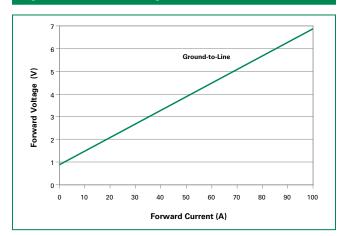


Figure 6: Forward Voltage vs. Forward Current



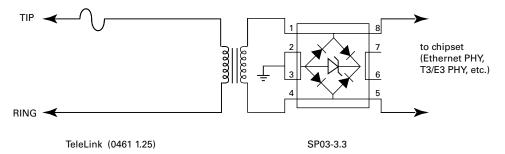
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Application Example

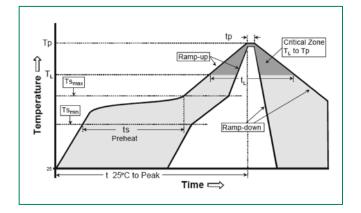
The following schematic shows a high-speed data interface protection solution. The SP03-3.3 provides both metallic (differential) and longitudinal (common mode) protection from lightning induced surge events. Its surge rating is compatible with the intra-building surge requirements of Telcordia's GR-1089-CORE, and the Basic Level

Recommendations of ITU K.20 and .21. This device protects against both positive and negative induced surge events. The TeleLink fuse provides overcurrent protection for the long term 50/60 Hz power fault events.



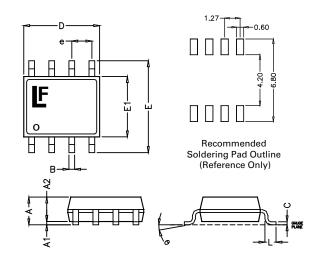
Soldering Parameters

Reflow Co	ndition	Pb – Free assembly	
	-Temperature Min (T _{s(min)})	150°C	
Pre Heat	-Temperature Max (T _{s(max)})	200°C	
	-Time (min to max) (t _s)	60 – 180 secs	
Average ramp up rate (Liquidus) Temp (T _L) to peak		3°C/second max	
T _{S(max)} to T _L	- Ramp-up Rate	3°C/second max	
Poflow	-Temperature (T _L) (Liquidus)	217°C	
Reflow	-Temperature (t _L)	60 – 150 seconds	
PeakTemperature (T _P)		250 ^{+0/-5} °C	
Time within 5°C of actual peak Temperature (t _p)		20 – 40 seconds	
Ramp-dow	n Rate	6°C/second max	
Time 25°C to peakTemperature (T _P)		8 minutes Max.	
Do not exc	eed	260°C	



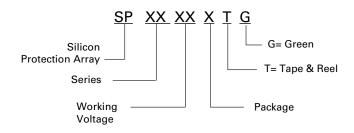


Package Dimensions - Mechanical Drawings and Recommended Solder Pad Outline



Package	MS-012 (SO-8)				
Pins	8				
JEDEC	MO-223 Issue A				
	Millin	netres	Inc	hes	
	Min	Max	Min	Max	
Α	1.35	1.75	0.053	0.069	
A 1	0.10	0.25	0.004	0.010	
A2	1.25	1.65	0.043	0.065	
В	0.31	0.51	0.012	0.020	
C	0.017	0.25	0.007	0.010	
D	4.80	5.00	0.189	0.197	
E	5.80	6.20	0.228	0.244	
E1	3.80	4.00	0.150	0.157	
е	1.27 BSC 0.050 BSC				
L	0.40 1.27 0.016 0.05				

Part Numbering System



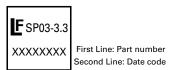
Product Characteristics

Lead Plating	Matte Tin
Lead Material	Copper Alloy
Lead Coplanarity	0.004 inches (0.102mm)
Subsitute Material	Silicon
Body Material	Molded Epoxy
Flammability	UL94-V-0

Notes:

- 1. All dimensions are in millimeters
- 2. Dimensions include solder plating.
- 3. Dimensions are exclusive of mold flash & metal burr.
- 4. All specifications comply to JEDEC SPEC MO-223 Issue A
- 5. Blo is facing up for mold and facing down for trim/form, i.e. reverse trim/form.
- 6. Package surface matte finish VDI 11-13.

Part Marking System



Ordering Information

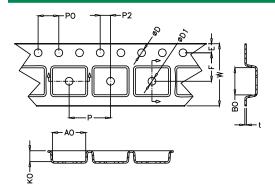
Part Number	Part Number Package		Min. Order Qty.
SP03-3.3BTG	SOIC Tape & Reel	SP03-3.3	2500

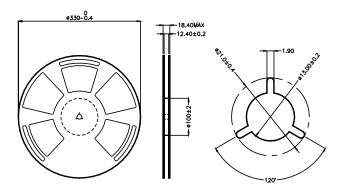
SPA[™] Silicon Protection Arrays





Embossed Carrier Tape & Reel Specification - SOIC Package





Dimensions

	Millimetres		Inc	hes	
	Min	Max	Min	Max	
E	1.65	1.85	0.065	0.073	
F	5.4	5.6	0.213	0.22	
P2	1.95	2.05	0.077	0.081	
D	1.5	1.6	0.059	0.063	
D1	1.50	Min	0.059 Min		
P0	3.9	4.1	0.154	0.161	
10P0	40.0 +	·/- 0.20	1.574 +/- 0.008		
W	11.9	12.1	0.468	0.476	
P	7.9	8.1	0.311	0.319	
A0	6.3	6.5	0.248	0.256	
В0	5.1	5.3	0.2	0.209	
K0	2	2.2	0.079	0.087	
t	0.30 +	·/- 0.05	0.012 +	/- 0.002	